

OKI Semiconductor
FEDD51V65400E-03
Issue Date: Jul. 19, 2005
MD51V65400E**16,777,216-Word × 4-Bit DYNAMIC RAM : FAST PAGE MODE TYPE****DESCRIPTION**

The MSD51V65400E is a 16,777,216-word × 4-bit dynamic RAM fabricated in Oki's silicon-gate CMOS technology. The MD51V65400E achieves high integration, high-speed operation, and low-power consumption because Oki manufactures the device in a quadruple-layer polysilicon/double-layer metal CMOS process. The MD51V65400E is available in a 32-pin plastic SOJ or 32-pin plastic TSOP.

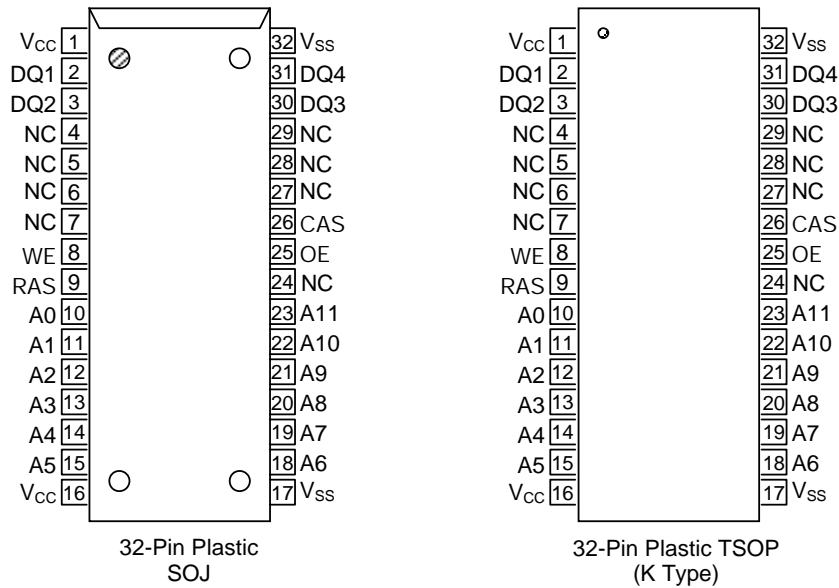
FEATURES

- 16,777,216-word × 4-bit configuration
 - Single 3.3V power supply, ±0.3V tolerance
 - Input : LVTTL compatible, low input capacitance
 - Output : LVTTL compatible, 3-state
 - Refresh :
 - RAS only refresh: :4096 cycles/64ms
 - CAS before RAS refresh, hidden refresh :4096 cycles/64ms
 - Fast page mode, read modify write capability
 - CAS before RAS refresh, hidden refresh, RAS-only refresh capability
 - Packages
 - 32-pin 400mil plastic SOJ (SOJ32-P-400-1.27) (Product : MD51V65400E-xxJA)
 - 32-pin 400mil plastic TSOP (TSOPII32-P-400-1.27-K) (Product : MD51V65400E-xxTA)
- xx indicates speed rank.

PRODUCT FAMILY

Family	Access Time (Max.)				Cycle Time (Min.)	Power Dissipation	
	t _{RAC}	t _{AA}	t _{CAC}	t _{OEA}		Operating (Max.)	Standby (Max.)
MD51V65400E	50ns	25ns	13ns	13ns	90ns	504mW	1.8mW
	60ns	30ns	15ns	15ns	110ns	432mW	

PIN CONFIGURATION (TOP VIEW)



Pin Name	Function
A0–A11	Address Input
RAS	Row Address Strobe
CAS	Column Address Strobe
DQ1–DQ4	Data Input/Data Output
OE	Output Enable
WE	Write Enable
V _{CC}	Power Supply (3.3V)
V _{SS}	Ground (0V)
NC	No Connection

Note : The same power supply voltage must be provided to every V_{CC} pin, and the same GND voltage level must be provided to every V_{SS} pin.

ELECTRICAL CHARACTERISTICS**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Voltage on Any Pin Relative to V_{SS}	V_{IN}, V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Voltage V_{CC} Supply Relative to V_{SS}	V_{CC}	-0.5 to 4.6	V
Short Circuit Output Current	I_{OS}	50	mA
Power Dissipation	P_{D^*}	1	W
Operating Temperature	T_{opr}	0 to 70	°C
Storage Temperature	T_{stg}	-55 to 150	°C

*: $T_a = 25^{\circ}\text{C}$ **RECOMMENDED OPERATING CONDITIONS** $(T_a = 0 \text{ to } 70^{\circ}\text{C})$

Parameter	Symbol	Min.	Typ.	Max.	Unit
Power Supply Voltage	V_{CC}	3.0	3.3	3.6	V
	V_{SS}	0	0	0	V
Input High Voltage	V_{IH}	2.0	—	$V_{CC} + 0.3^{*1}$	V
Input Low Voltage	V_{IL}	-0.3^{*2}	—	0.8	V

Notes: *1. The input voltage is $V_{CC} + 1.0\text{V}$ when the pulse width is less than 20ns (the pulse width is with respect to the point at which V_{CC} is applied).

*2. The input voltage is $V_{SS} - 1.0\text{V}$ when the pulse width is less than 20ns (the pulse width respect to the point at which V_{SS} is applied).

PIN CAPACITANCE $(V_{CC} = 3.3\text{V} \pm 0.3\text{V}, T_a = 25^{\circ}\text{C}, f = 1 \text{ MHz})$

Parameter	Symbol	Min.	Max.	Unit
Input Capacitance (A0 – A11)	C_{IN1}	—	5	pF
Input Capacitance (RAS, CAS, WE, OE)	C_{IN2}	—	7	pF
Output Capacitance (DQ1 – DQ4)	$C_{I/O}$	—	7	pF

DC CHARACTERISTICS

(V_{CC} = 3.3V ± 0.3V, Ta = 0 to 70°C)

Parameter	Symbol	Condition	MD51V65400 E-50		MD51V65400 E-60		Unit	Note
			Min.	Max.	Min.	Max.		
Output High Voltage	V _{OH}	I _{OH} = -2.0mA	2.4	V _{CC}	2.4	V _{CC}	V	
Output Low Voltage	V _{OL}	I _{OL} = 2.0mA	0	0.4	0	0.4	V	
Input Leakage Current	I _{LI}	0V ≤ V _I ≤ V _{CC} + 0.3V; All other pins not under test = 0V	- 10	10	- 10	10	μA	
Output Leakage Current	I _{LO}	DQ disable 0V ≤ V _O ≤ V _{CC}	- 10	10	- 10	10	μA	
Average Power Supply Current (Operating)	I _{CC1}	RAS, CAS cycling, t _{RC} = Min.	—	140	—	120	mA	1,2
Power Supply Current (Standby)	I _{CC2}	RAS, CAS = V _{IH}	—	1	—	1	mA	1
		RAS, CAS ≥ V _{CC} - 0.2V	—	0.5	—	0.5		
Average Power Supply Current (RAS-only Refresh)	I _{CC3}	RAS cycling, CAS = V _{IH} , t _{RC} = Min.	—	140	—	120	mA	1,2
Power Supply Current (Standby)	I _{CC5}	RAS = V _{IH} , CAS = V _{IL} , DQ = enable	—	5	—	5	mA	1
Average Power Supply Current (CAS before RAS Refresh)	I _{CC6}	RAS = cycling, CAS before RAS	—	140	—	120	mA	1,2
Average Power Supply Current (Fast Page Mode)	I _{CC7}	RAS = V _{IL} , CAS cycling, t _{PC} = Min.	—	90	—	80	mA	1,3

- Notes: 1. I_{CC} Max. is specified as I_{CC} for output open condition.
2. The address can be changed once or less while RAS = V_{IL}.
3. The address can be changed once or less while CAS = V_{IH}.

AC CHARACTERISTICS (1/2)

 $(V_{CC} = 3.3V \pm 0.3V, T_a = 0 \text{ to } 70^\circ\text{C})$ Note1,2,3

Parameter	Symbol	MD51V65400 E-50		MD51V65400 E-60		Unit	Note
		Min.	Max.	Min.	Max.		
Random Read or Write Cycle Time	t_{RC}	90	—	110	—	ns	
Read Modify Write Cycle Time	t_{RWC}	131	—	155	—	ns	
Fast Page Mode Cycle Time	t_{PC}	35	—	40	—	ns	
Fast Page Mode Read Modify Write Cycle Time	t_{PRWC}	76	—	85	—	ns	
Access Time from RAS	t_{RAC}	—	50	—	60	ns	4, 5, 6
Access Time from CAS	t_{CAC}	—	13	—	15	ns	4, 5
Access Time from Column Address	t_{AA}	—	25	—	30	ns	4, 6
Access Time from CAS Precharge	t_{CPA}	—	30	—	35	ns	4
Access Time from OE	t_{OEA}	—	13	—	15	ns	4
Output Low Impedance Time from CAS	t_{CLZ}	0	—	0	—	ns	4
CAS to Data Output Buffer Turn-off Delay Time	t_{OFF}	0	13	0	15	ns	7
OE to Data Output Buffer Turn-off Delay Time	t_{OEZ}	0	13	0	15	ns	7
Transition Time	t_T	3	50	3	50	ns	3
Refresh Period	t_{REF}	—	64	—	64	ms	
RAS Precharge Time	t_{RP}	30	—	40	—	ns	
RAS Pulse Width	t_{RAS}	50	10,000	60	10,000	ns	
RAS Pulse Width (Fast Page Mode)	t_{RASP}	50	100,000	60	100,000	ns	
RAS Hold Time	t_{RSH}	13	—	15	—	ns	
RAS Hold Time referenced to OE	t_{ROH}	13	—	15	—	ns	
CAS Precharge Time (Fast Page Mode)	t_{CP}	7	—	10	—	ns	
CAS Pulse Width	t_{CAS}	13	10,000	15	10,000	ns	
CAS Hold Time	t_{CSH}	50	—	60	—	ns	
CAS to RAS Precharge Time	t_{CRP}	5	—	5	—	ns	
RAS Hold Time from CAS Precharge	t_{RHCP}	30	—	35	—	ns	
RAS to CAS Delay Time	t_{RCD}	17	37	20	45	ns	5
RAS to Column Address Delay Time	t_{RAD}	12	25	15	30	ns	6
Row Address Set-up Time	t_{ASR}	0	—	0	—	ns	

AC CHARACTERISTICS (2/2)

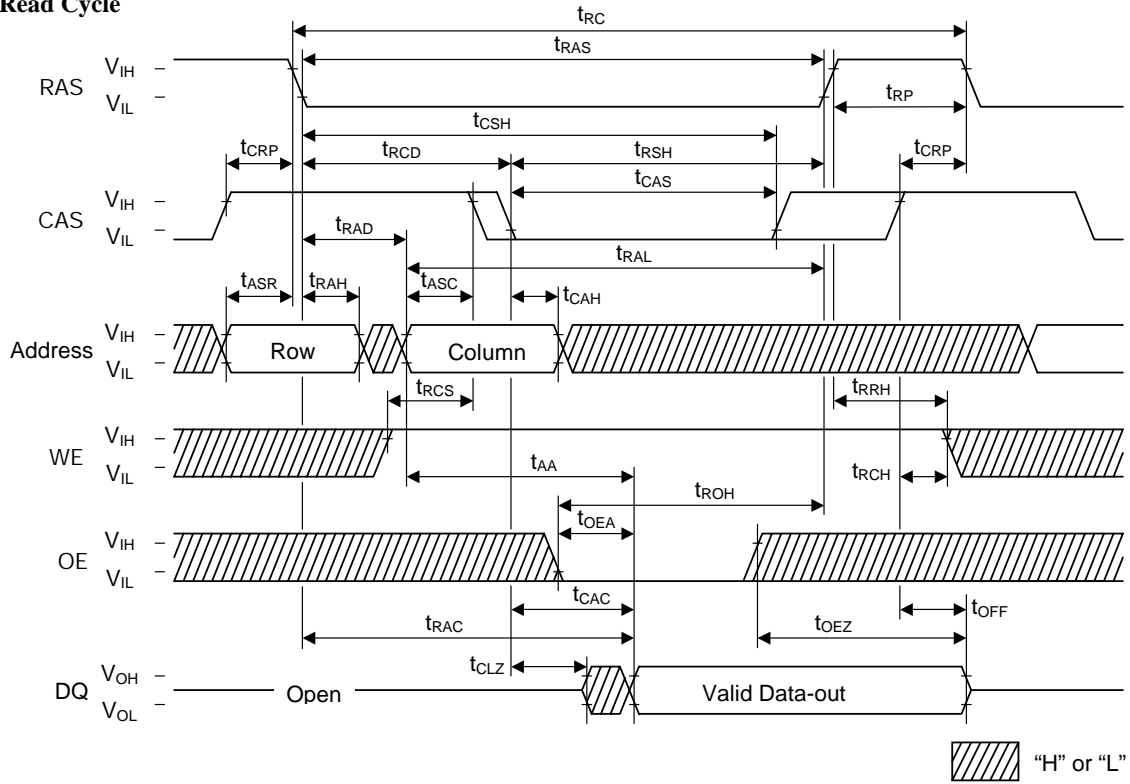
 $(V_{CC} = 3.3V \pm 0.3V, T_a = 0 \text{ to } 70^\circ\text{C})$ Note1,2,3

Parameter	Symbol	MD51V65400 E-50		MD51V65400 E-60		Unit	Note
		Min.	Max.	Min.	Max.		
Row Address Hold Time	t _{RAH}	7	—	10	—	ns	
Column Address Set-up Time	t _{ASC}	0	—	0	—	ns	
Column Address Hold Time	t _{CAH}	7	—	10	—	ns	
Column Address to RAS Lead Time	t _{RAL}	25	—	30	—	ns	
Read Command Set-up Time	t _{RCS}	0	—	0	—	ns	
Read Command Hold Time	t _{RCH}	0	—	0	—	ns	8
Read Command Hold Time referenced to RAS	t _{RRH}	0	—	0	—	ns	8
Write Command Set-up Time	t _{WCS}	0	—	0	—	ns	9
Write Command Hold Time	t _{WCH}	7	—	10	—	ns	
Write Command Pulse Width	t _{WP}	7	—	10	—	ns	
OE Command Hold Time	t _{OEH}	13	—	15	—	ns	
Write Command to RAS Lead Time	t _{RWL}	13	—	15	—	ns	
Write Command to CAS Lead Time	t _{CWL}	13	—	15	—	ns	
Data-in Set-up Time	t _{DS}	0	—	0	—	ns	10
Data-in Hold Time	t _{DH}	7	—	10	—	ns	10
OE to Data-in Delay Time	t _{OED}	13	—	15	—	ns	
CAS to WE Delay Time	t _{CWD}	36	—	40	—	ns	9
Column Address to WE Delay Time	t _{AWD}	48	—	55	—	ns	9
RAS to WE Delay Time	t _{RWD}	73	—	85	—	ns	9
CAS Precharge WE Delay Time	t _{CPWD}	53	—	60	—	ns	9
CAS Active Delay Time from RAS Precharge	t _{RPC}	5	—	5	—	ns	
RAS to CAS Set-up Time (CAS before RAS)	t _{CSR}	10	—	10	—	ns	
RAS to CAS Hold Time (CAS before RAS)	t _{CHR}	10	—	10	—	ns	
WE to RAS Hold Time(CAS before RAS)	t _{WRP}	10	—	10	—	ns	
WE Hold Time(CAS before RAS)	t _{WRH}	10	—	10	—	ns	

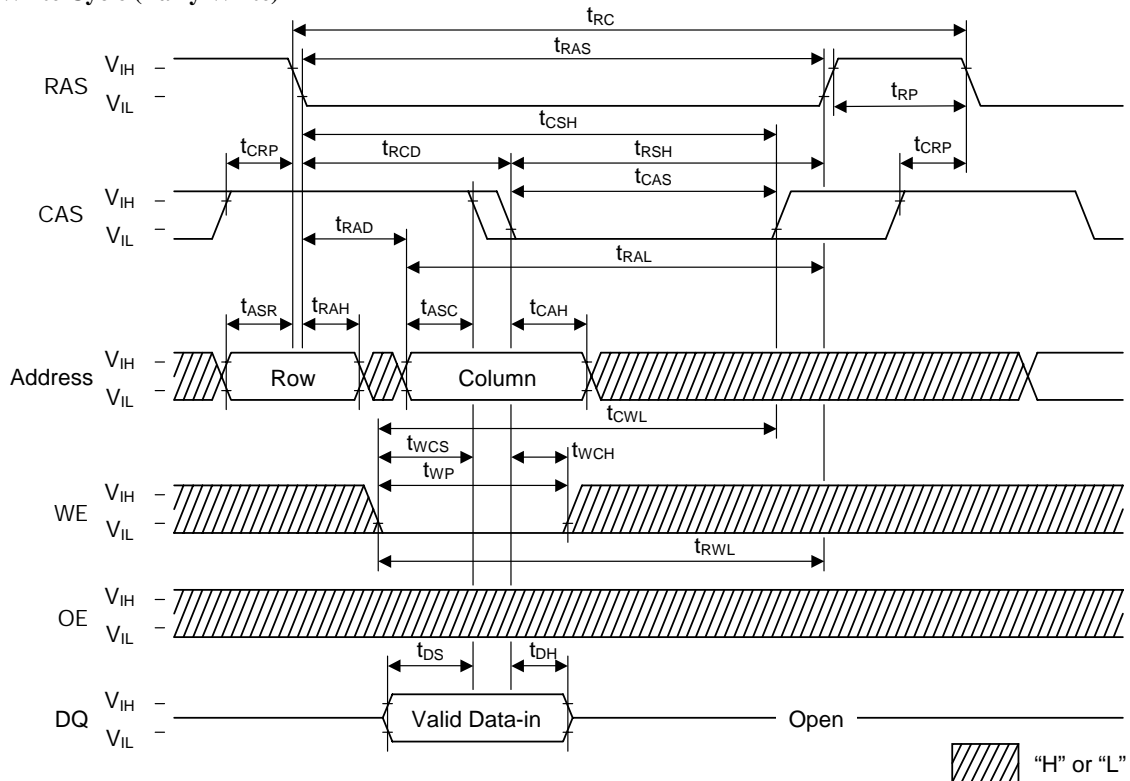
- Notes:
1. A start-up delay of 200 μ s is required after power-up, followed by a minimum of eight initialization cycles (RAS-only refresh or CAS before RAS refresh) before proper device operation is achieved.
 2. The AC characteristics assume $t_T = 5$ ns.
 3. V_{IH} (Min.) and V_{IL} (Max.) are reference levels for measuring input timing signals. Transition times (t_T) are measured between V_{IH} and V_{IL} .
 4. This parameter is measured with a load circuit equivalent to 1 TTL load and 100pF. The output timing reference levels are $V_{OH}=2.0$ and $V_{OL}=0.8$ V.
 5. Operation within the t_{RCD} (Max.) limit ensures that t_{RAC} (Max.) can be met. t_{RCD} (Max.) is specified as a reference point only. If t_{RCD} is greater than the specified t_{RCD} (Max.) limit, then the access time is controlled by t_{CAC} .
 6. Operation within the t_{RAD} (Max.) limit ensures that t_{RAC} (Max.) can be met. t_{RAD} (Max.) is specified as a reference point only. If t_{RAD} is greater than the specified t_{RAD} (Max.) limit, then the access time is controlled by t_{AA} .
 7. t_{OFF} (Max.) and t_{OEZ} (Max.) define the time at which the output achieved the open circuit condition and are not referenced to output voltage levels.
 8. t_{RCH} or t_{RRH} must be satisfied for a read cycle.
 9. t_{WCS} , t_{CWD} , t_{RWD} , t_{AWD} and t_{CPWD} are not restrictive operating parameters. They are included in the data sheet as electrical characteristics only. If $t_{WCS} \geq t_{WCS}$ (Min.), then the cycle is an early write cycle and the data out will remain open circuit (high impedance) throughout the entire cycle. If $t_{CWD} \geq t_{CWD}$ (Min.), $t_{RWD} \geq t_{RWD}$ (Min.), $t_{AWD} \geq t_{AWD}$ (Min.) and $t_{CPWD} \geq t_{CPWD}$ (Min.), then the cycle is a read modify write cycle and data out will contain data read from the selected cell; if neither of the above sets of conditions is satisfied, then the condition of the data out (at access time) is indeterminate.
 10. These parameters are referenced to the CAS, leading edges in an early write cycle, and to the WE leading edge in an OE control write cycle, or a read modify write cycle.

TIMING CHART

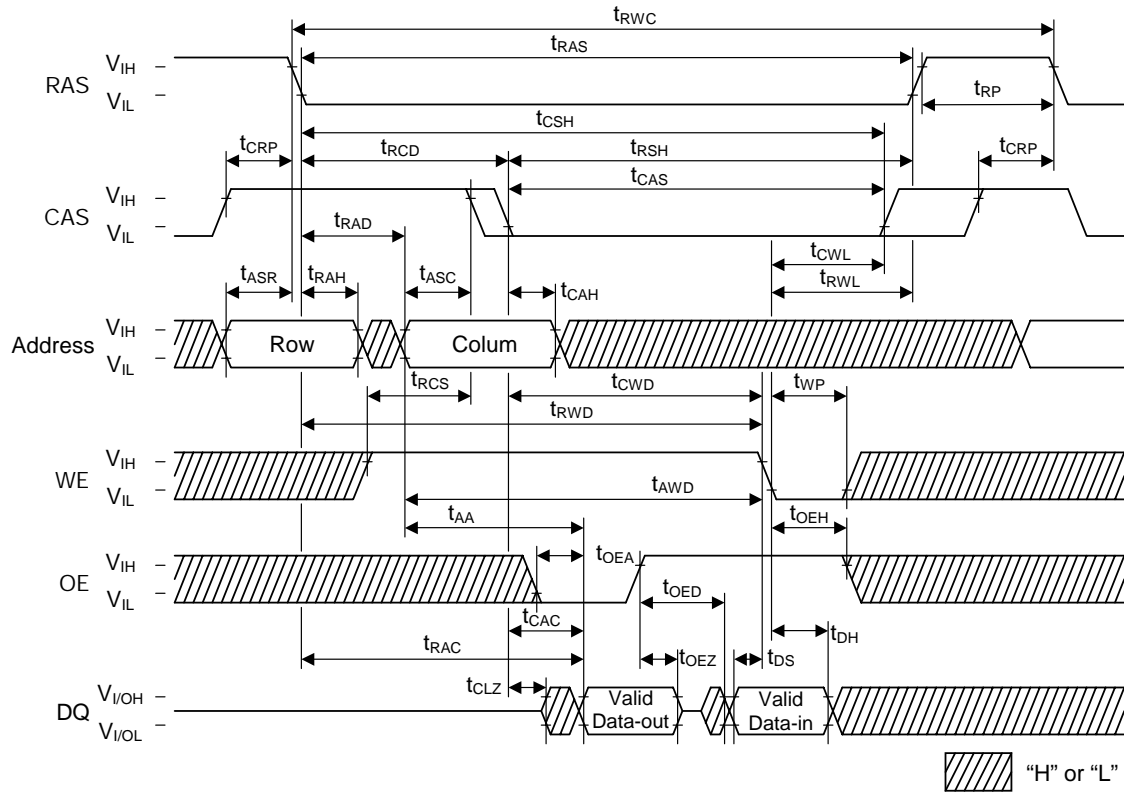
Read Cycle



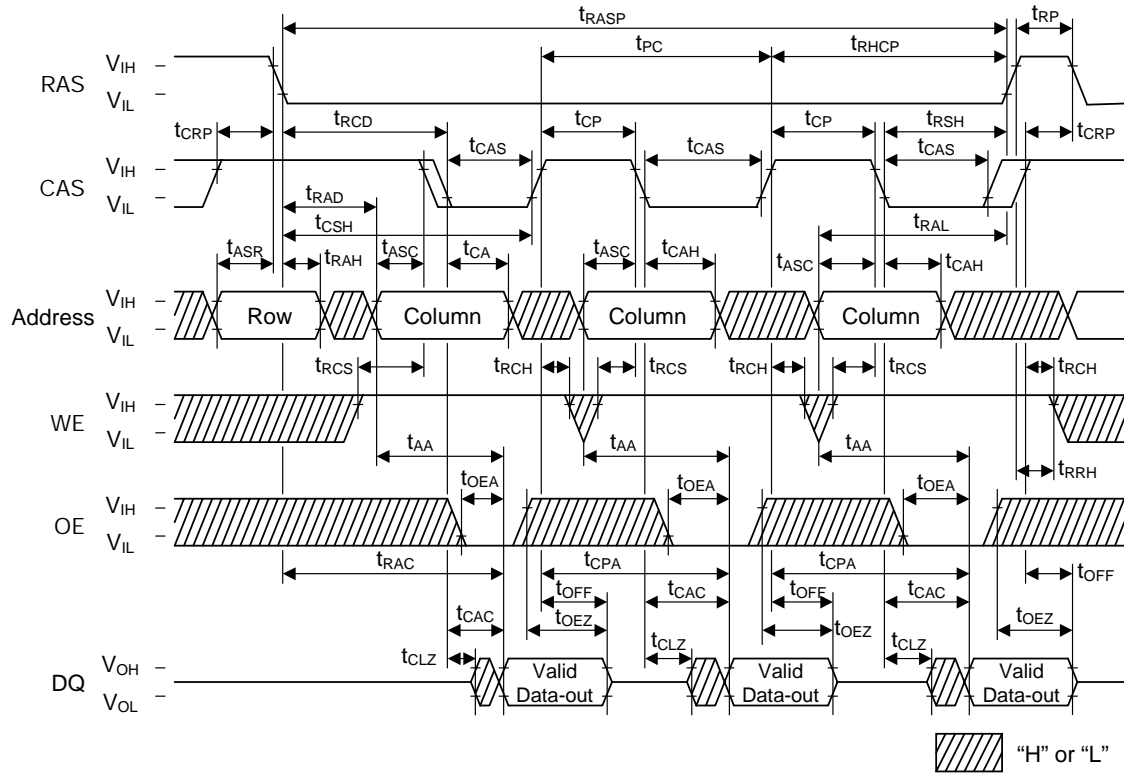
Write Cycle (Early Write)



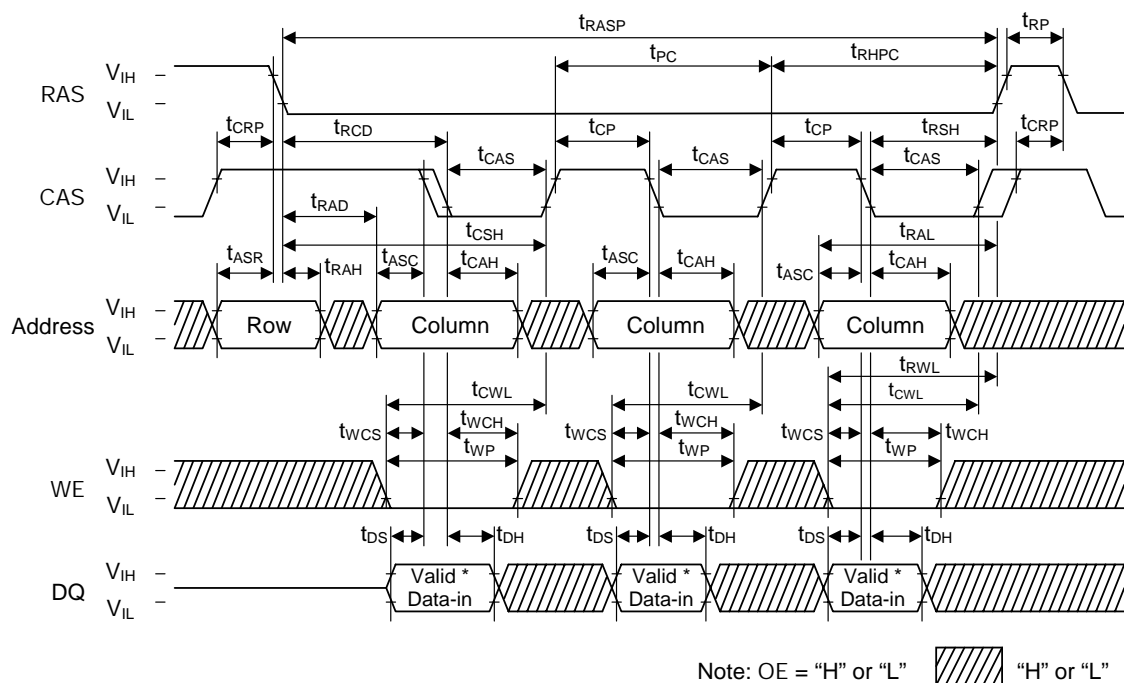
Read Modify Write Cycle



Fast Page Mode Read Cycle

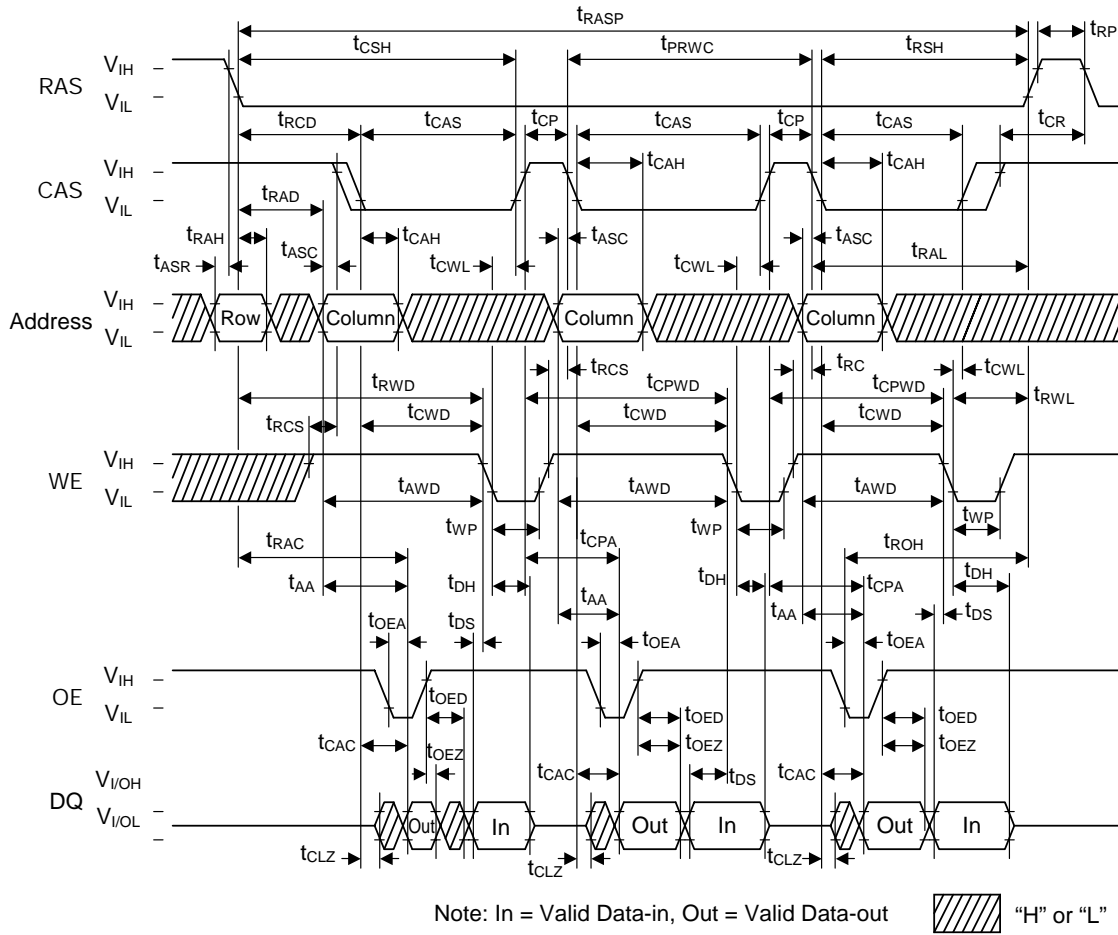


Fast Page Mode Write Cycle (Early Write)

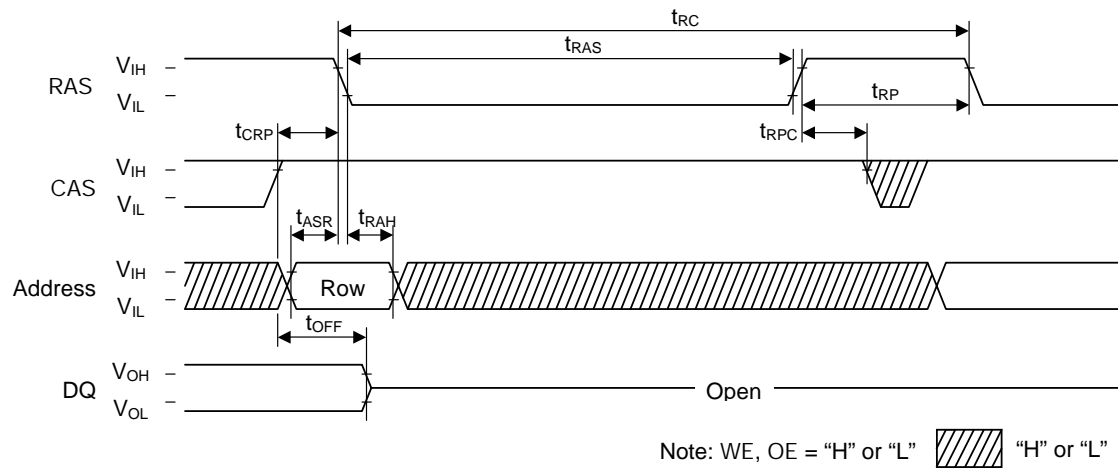


Note: OE = "H" or "L" "H" or "L"

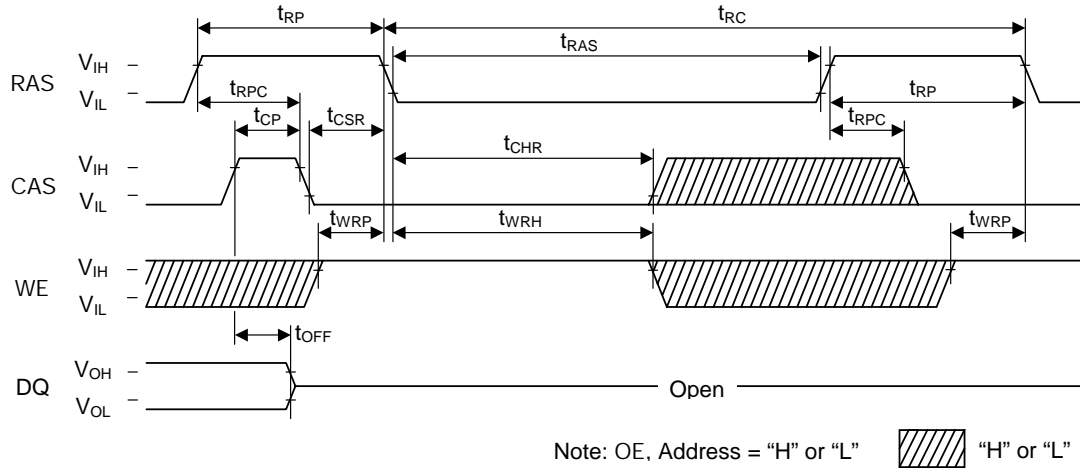
Fast Page Mode Read Modify Write Cycle



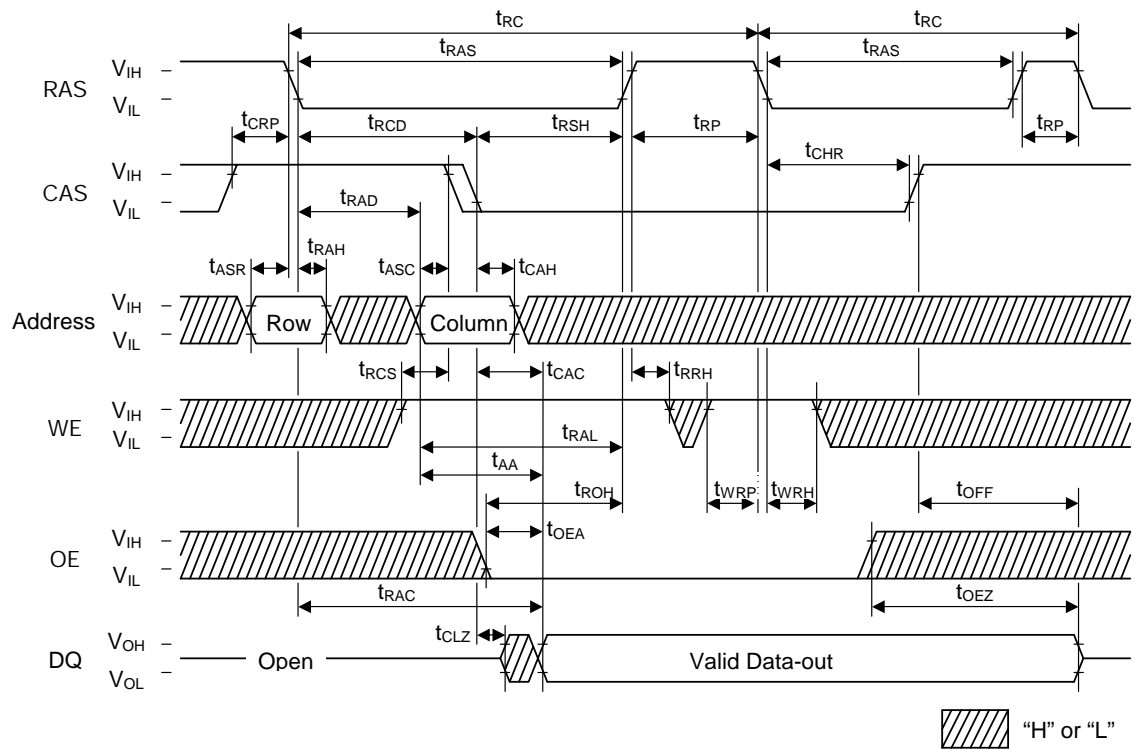
RAS-only Refresh Cycle



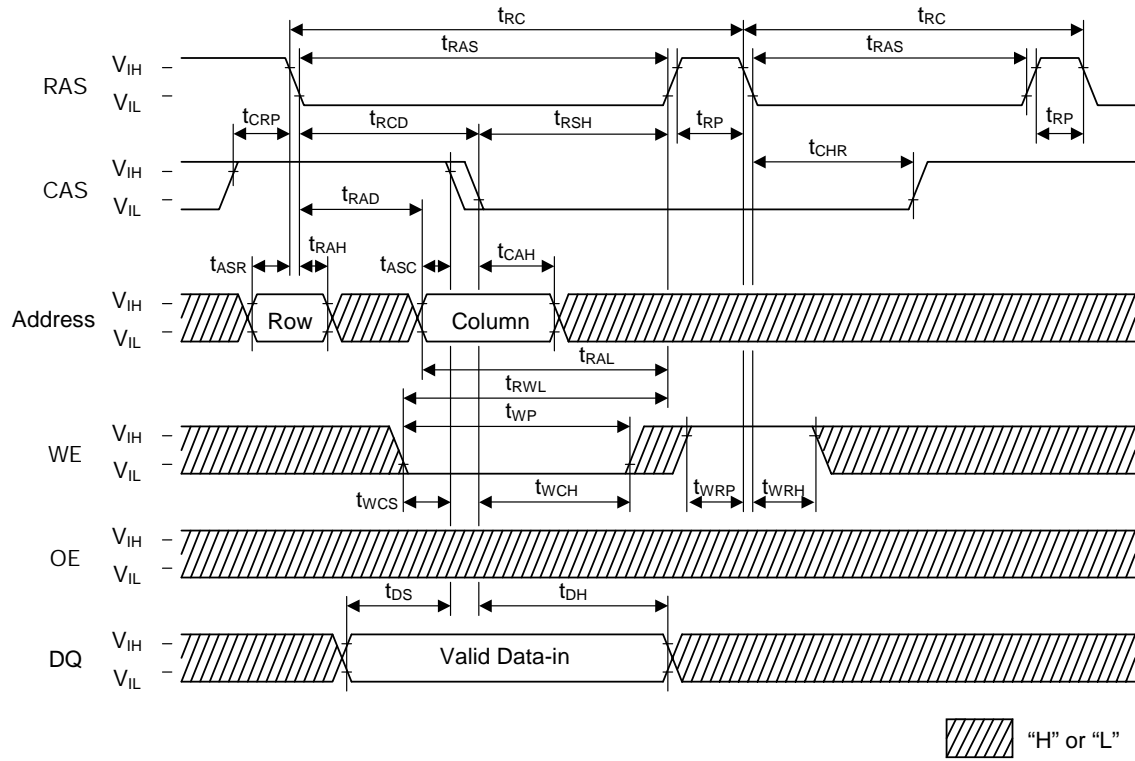
CAS before RAS Refresh Cycle



Hidden Refresh Read Cycle



Hidden Refresh Write Cycle



REVISION HISTORY

Document No.	Date	Page		Description
		Previous Edition	Current Edition	
PEDD51V65400E-01	Jul. 1, 2002	–	–	Preliminary edition 1
FEDD51V65400E-01	Dec. 27, 2002	–	–	Final edition
FEDD51V65400E-02	Oct. 30, 2003	–	–	Fixed errata
FEDD51V65400E-03	Jul. 19, 2005	3	–	Block Diagram deleted

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